

# Materials Data in Electrical Device Design

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# / Materials Data in Electrical Device Design

- The Importance of Materials & Materials Data
- Materials Data Management
- Integrated Computational Materials Engineering (ICME)
- Case Study: CORNET Project & Organic Electronics

# Why materials information matters

Growth

Profit

Risk

Understand materials behaviour to increase product lifetime

Lightweight with composites for competitive advantage

Specify the right materials for global manufacturing locations

Innovate with additive manufacturing

Minimize regulatory risk due to restricted substances

Reduce environmental impact, gain market share

Make it at lower cost by substituting materials

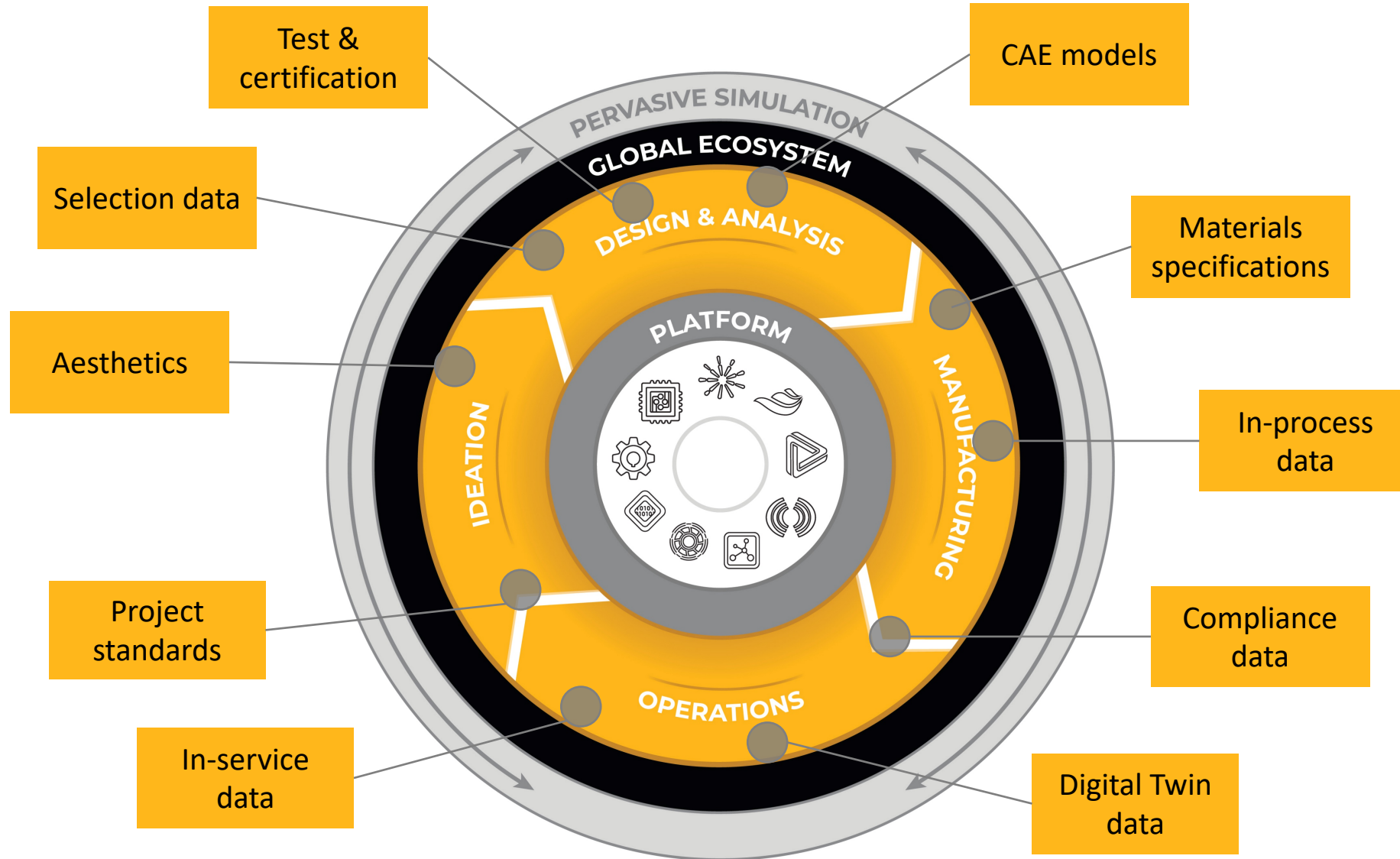
Ensure ROI from simulation, with the right input data

Reduce materials-related warranty issues or recalls

Avoid risks to human health

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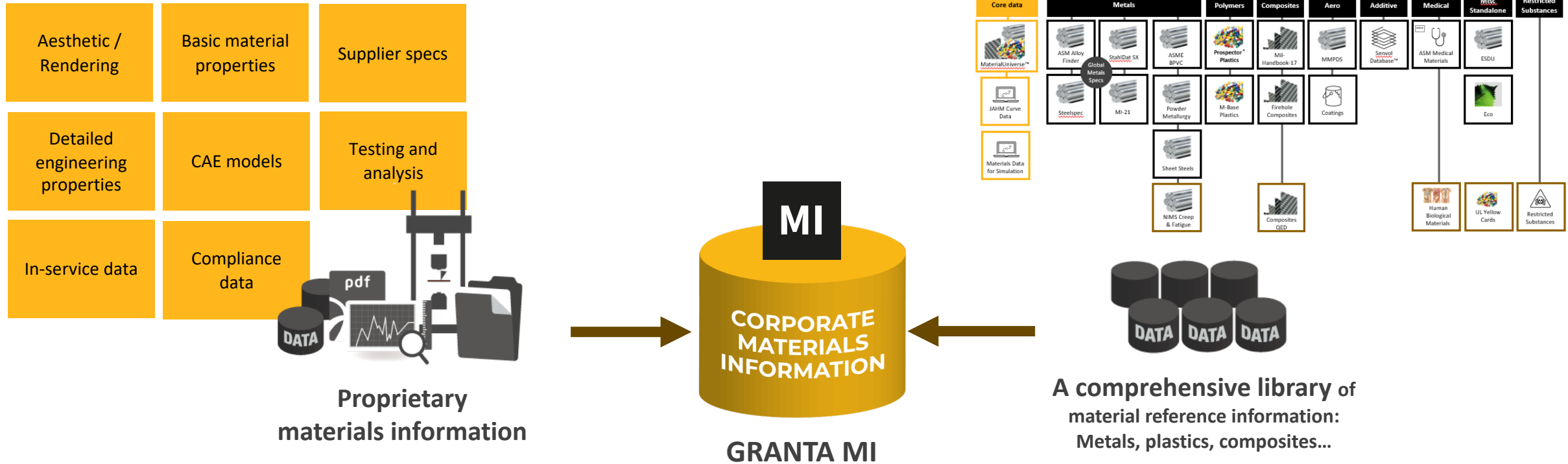
# Materials information throughout the product lifecycle



Example material data sets



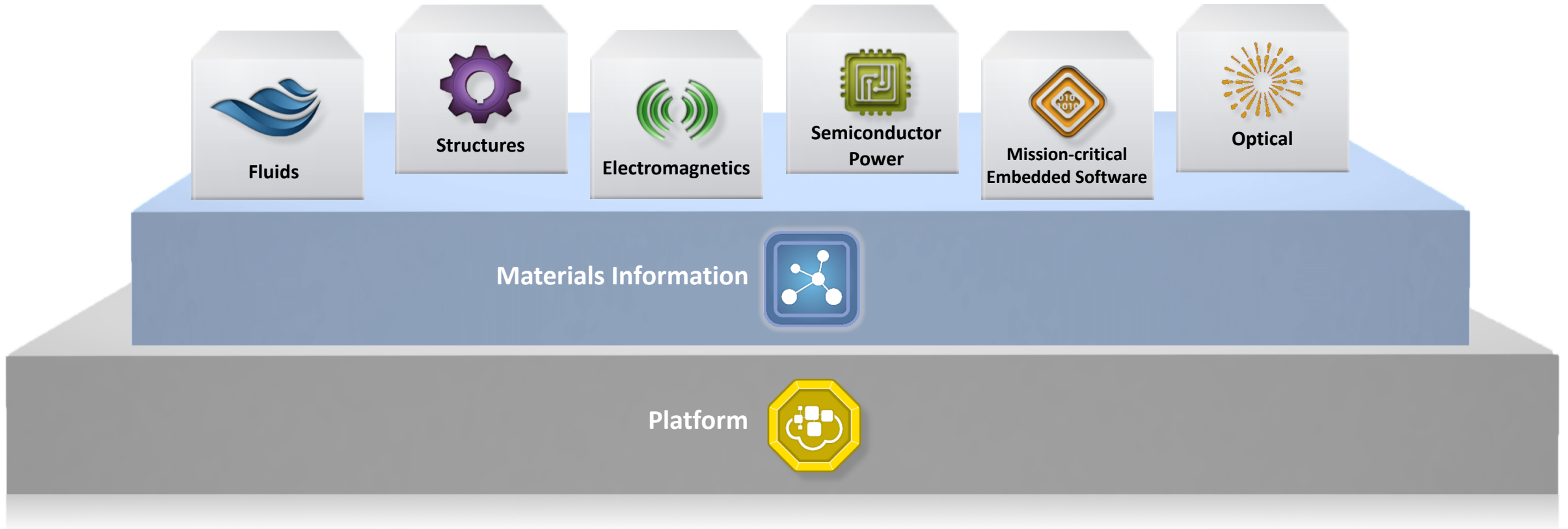
# GRANTA MI – ‘gold source’ for corporate material intelligence



## Critical system requirements:

- Specialist materials data structures
- Tools to manage the materials data lifecycle
- Full traceability
- Access and change control, workflow

# ANSYS Granta: Materials Information for all Physics

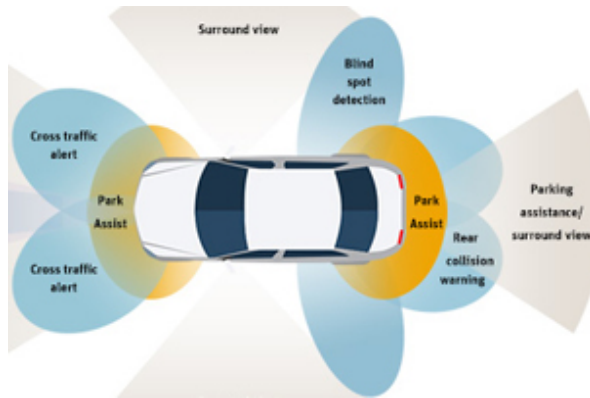


# Materials challenges in EM design

## Automotive Radar

Used for safety, navigation and driver assistance

- Antenna and sensors in close proximity to structure & bodywork
- Need to control scattering of beam
- Need *dielectric properties* of *automotive materials* at 24 & 76 GHz



## High Speed PCBs

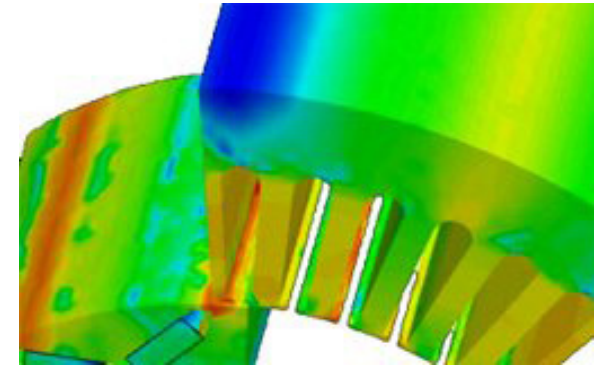
5G networks increasing data rates and frequency of PCBs

- Materials start to influence performance: PCB materials, effects of weave in PCB, surface roughness of copper
- SI simulation needs *dielectric properties* of *PCB* and *packaging materials* over a wide frequency range and which meet causality requirements

## Electric Motor Design

Automotive require lightweight, compact and quiet motors

- Coupled EM, mechanical and thermal analysis need multi-physics approach to materials
- *Magnetic, Mechanical* and *Thermal* properties required, all at elevated temperatures

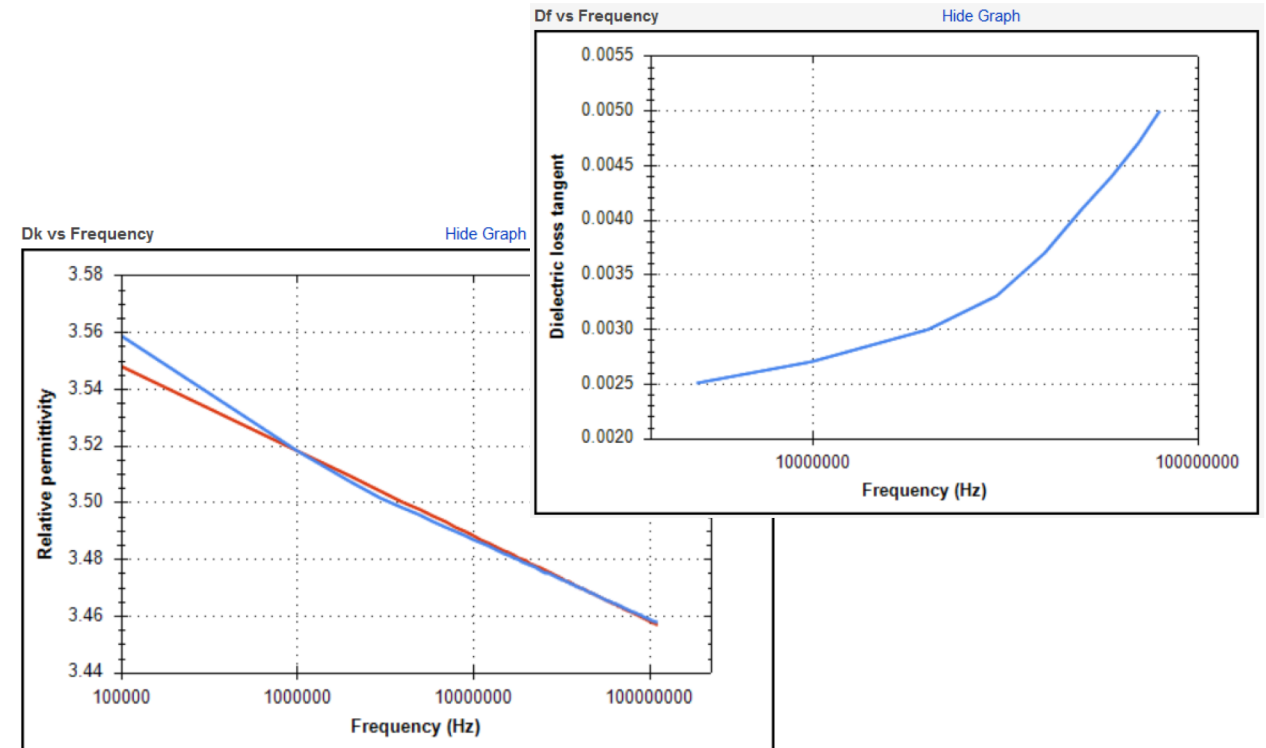
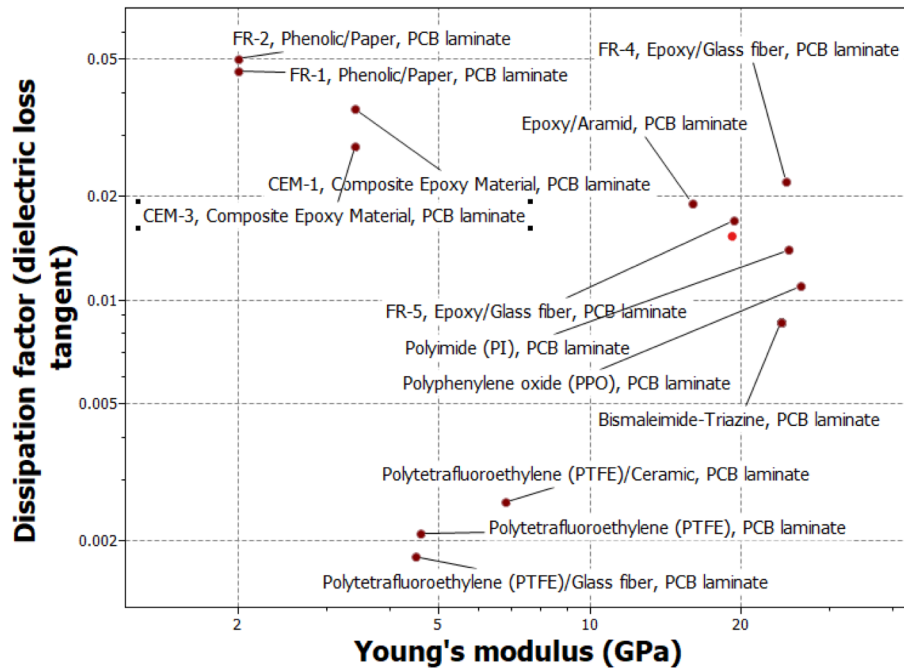


# Importance of accurate materials properties: PCB Laminates

- Variation with material grade

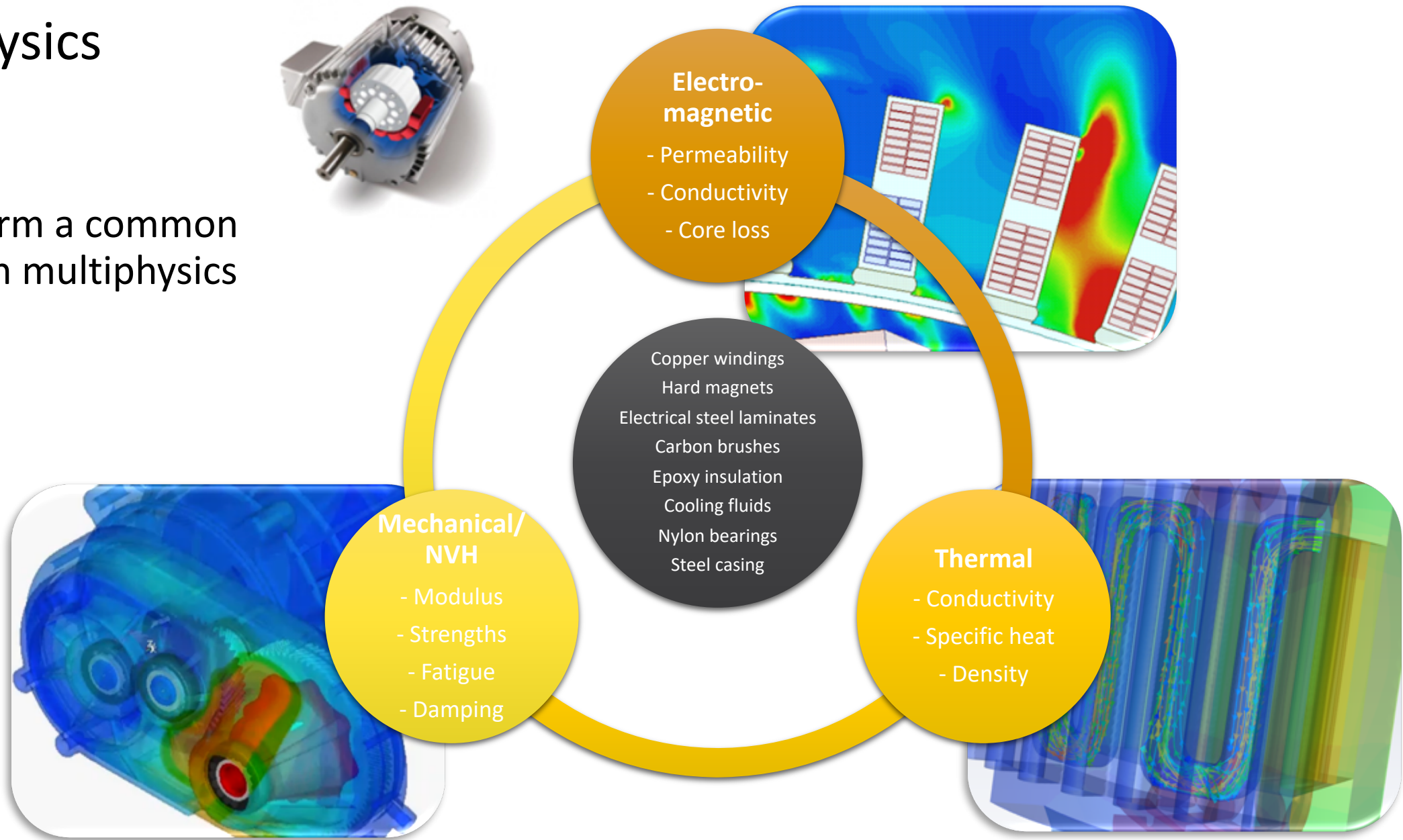
- Resin & resin content
- Reinforcement type and style
- Thickness of laminate and copper
- Surface roughness

- Variation with operating condition

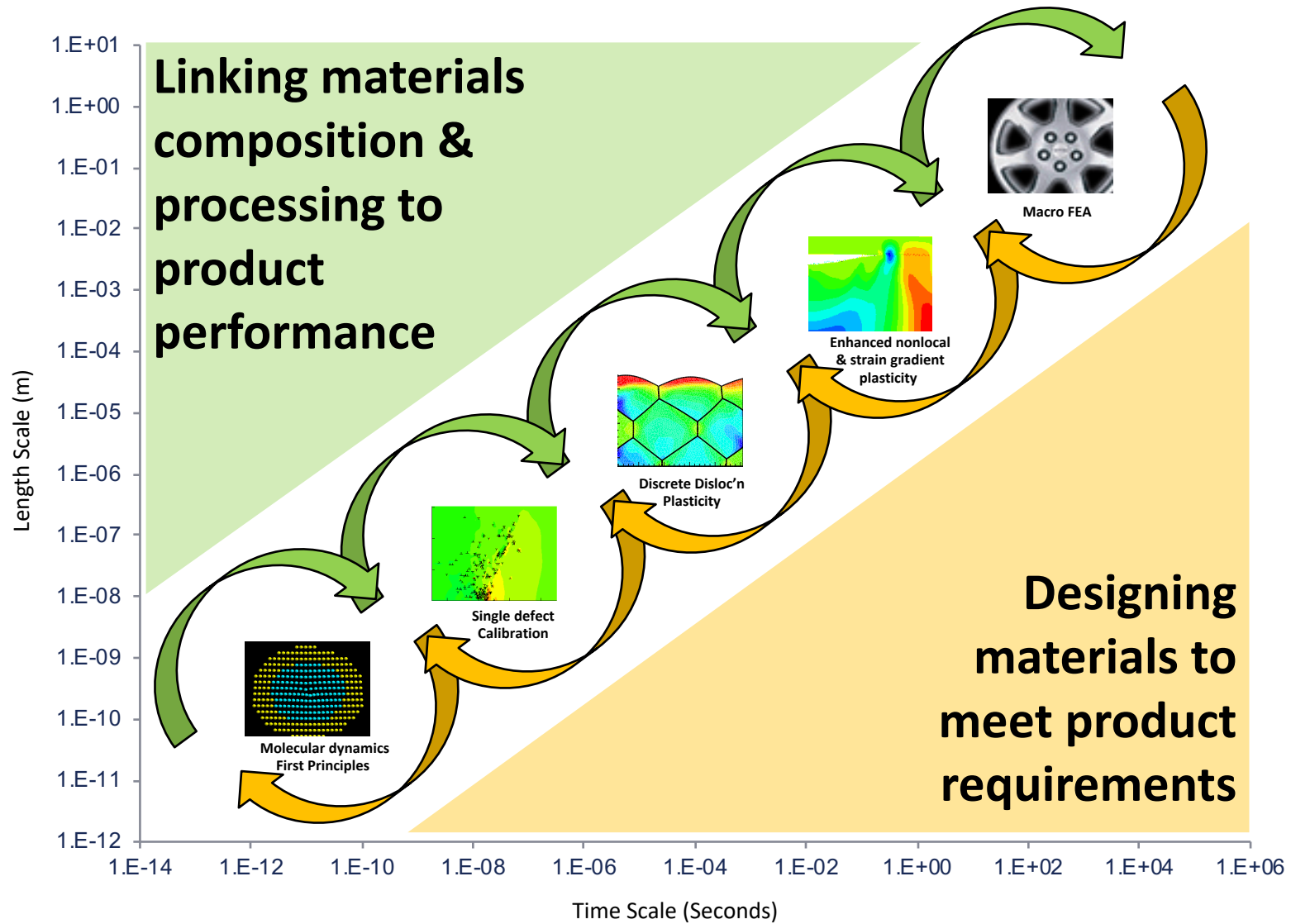


# Multiphysics

Materials form a common link between multiphysics simulations

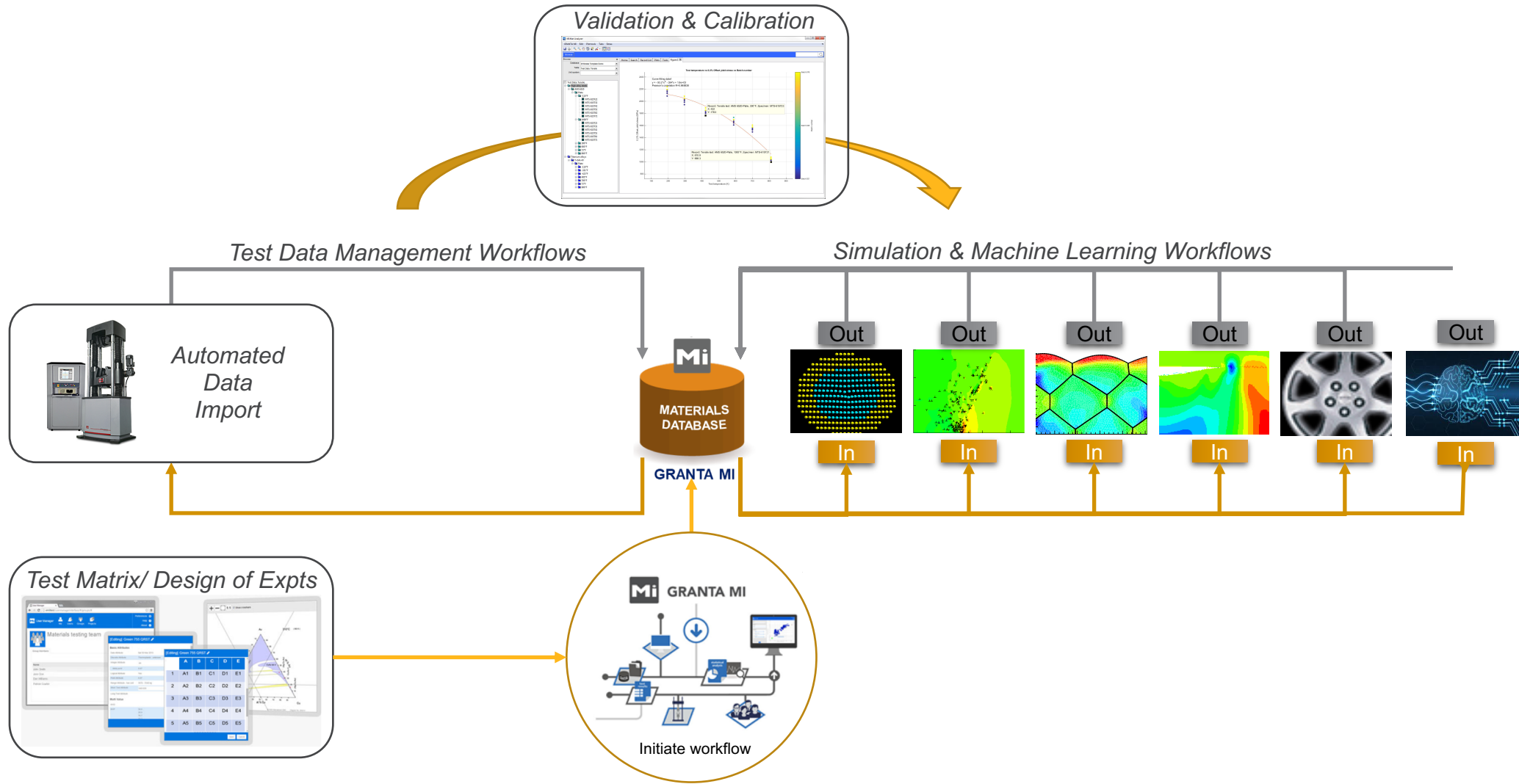


# Multiscale modelling





# ICME: Integrated Computational Materials Engineering





# Case Study: Materials Data for Organic Electronics

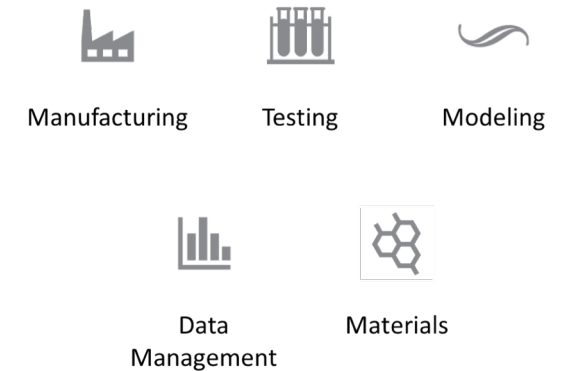
CORNET Project



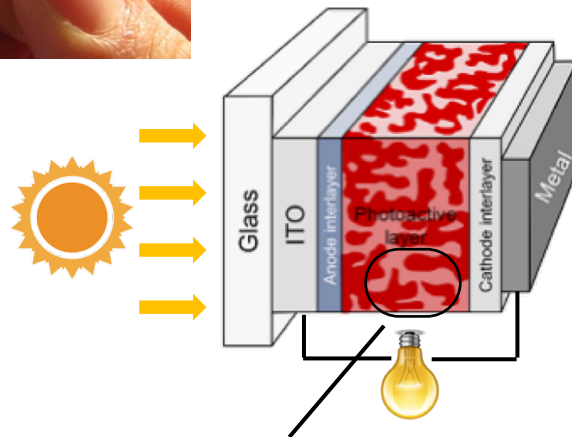
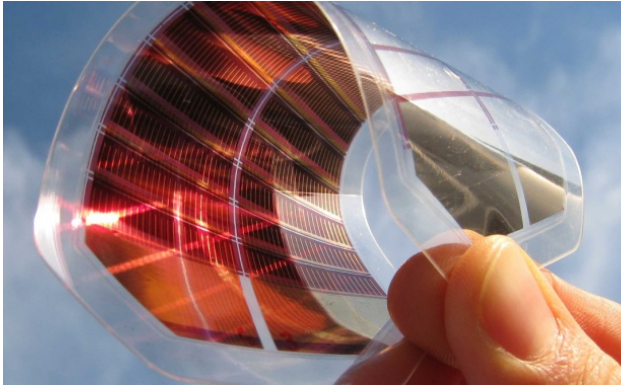
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# CORNET Project

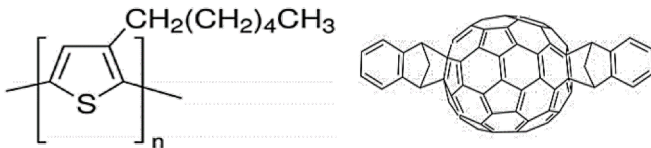
- CORNET Project : Multiscale Modelling and Characterization to Optimize the Manufacturing Processes of Organic Electronics Materials and Devices
- It is a 3 years research project funded by European Union under Horizon 2020 funding scheme (DT-NMBP-07-2017 call)
- It covers the triangle of manufacturing, modelling and experimentation to optimize the OPVs, PPVs, OLEDs
- It aims to develop a data management system for Organic Electronics (OE) materials information accommodating manufacturing process parameters, test and simulation data and agreed metadata
- <https://www.cornet-project.eu/>



# CORNET: Organic electronic industry challenges



**Photoactive layer:**  
Amorphous Donor-Acceptor blend



## Organic Photovoltaics (OPVs)

- Light weight, flexible, low cost, printable
- Environmentally friendly
- Easy installation, ideal for complex surfaces

But...

- Low Power Conversion Efficiencies (<15%)
- Poor lifetimes (~1yr)
- Low carrier mobilities ( $10^{-6}$ - $10^{-2}$ cm<sup>2</sup>/Vs)

**OPV Performance:** strongly depends on materials used and processing conditions



**Non-Global, Non-Well-defined materials and process models as in Si-based PVs**

# CORNET: Multiscale Modelling of OE materials

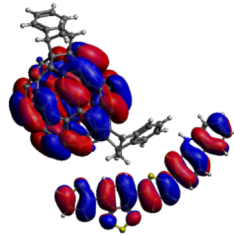


from electrons...

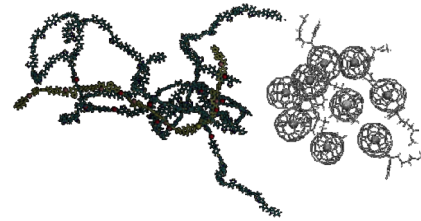
... to full device characterization



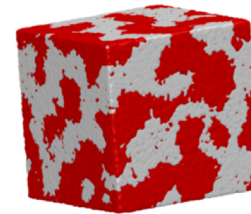
Schrodinger equation for electrons



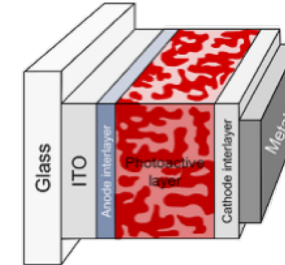
equations of motion for atoms & molecules



domains & stochastic charge transport

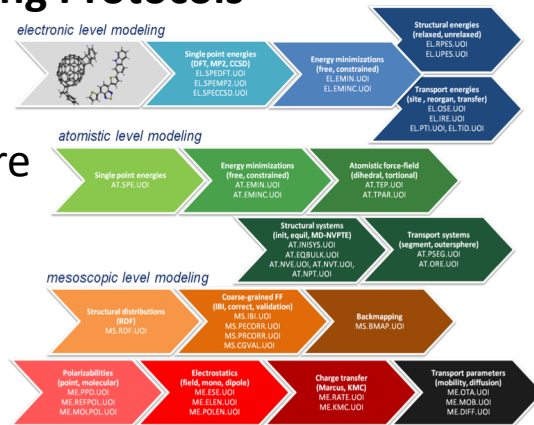


Drift-diffusion for carriers



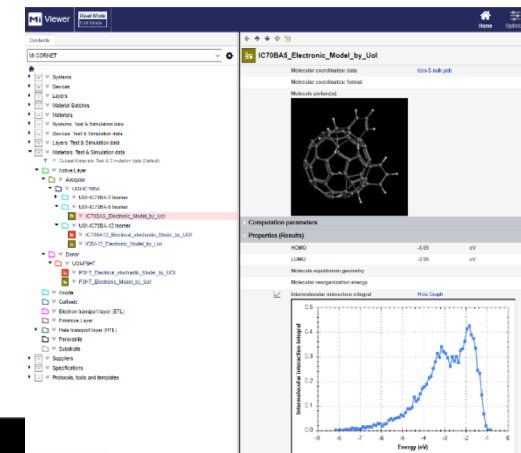
## Modelling Protocols

- Physics
- Approximations
- Numerical procedure



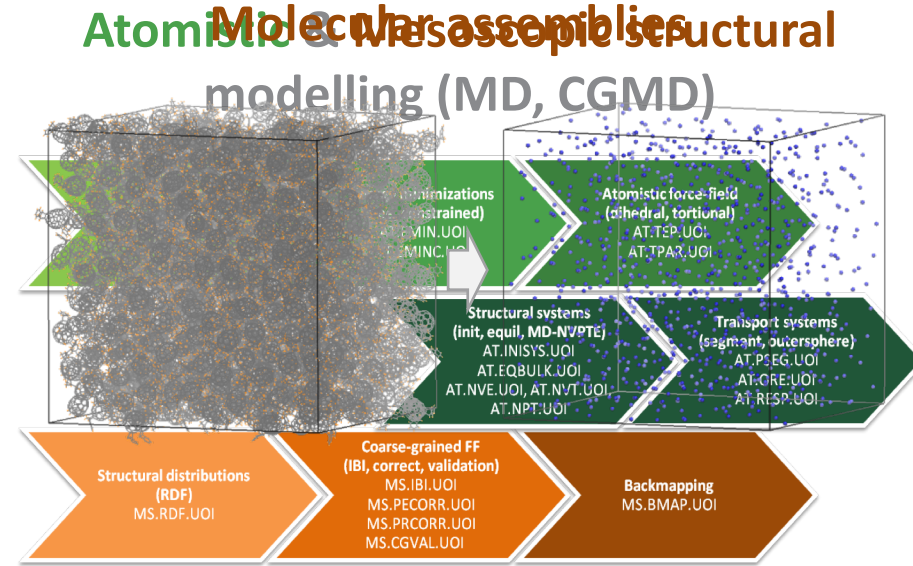
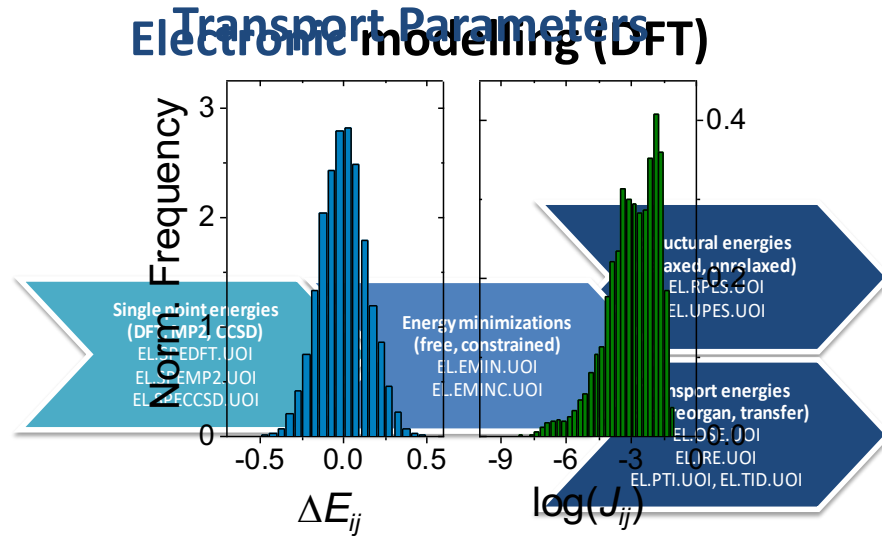
## Data Management

- Data analysis tools
- Visualization
- Post-Processing





# CORNET: Multiscale Modelling Protocols for OEs



Charge transport within  
Marcus theory

Mesoscale electrical model

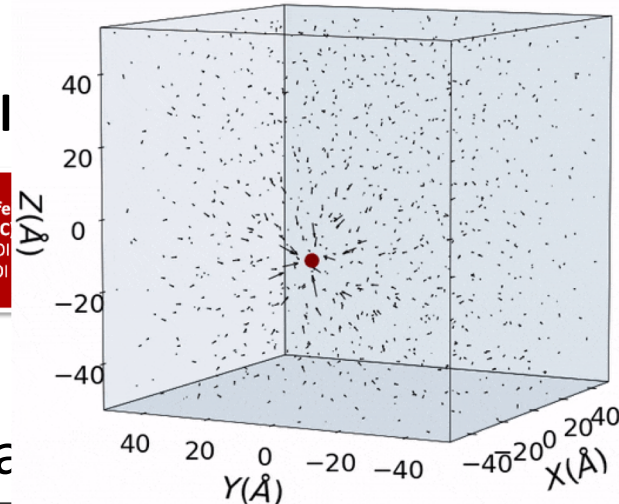
$$W_{ij} = \frac{2\pi}{\hbar} \frac{|J_{ij}|^2}{\sqrt{4\pi\lambda_{ij}k_B T}} \exp \left[ -\frac{(\Delta E_{ij} + \lambda_{ij})^2}{4\lambda_{ij}k_B T} \right]$$

Polarizabilities (point, molecular)  
ME.PPD.UOI  
ME.REFPOL.UOI  
ME.MOLPOL.UOI

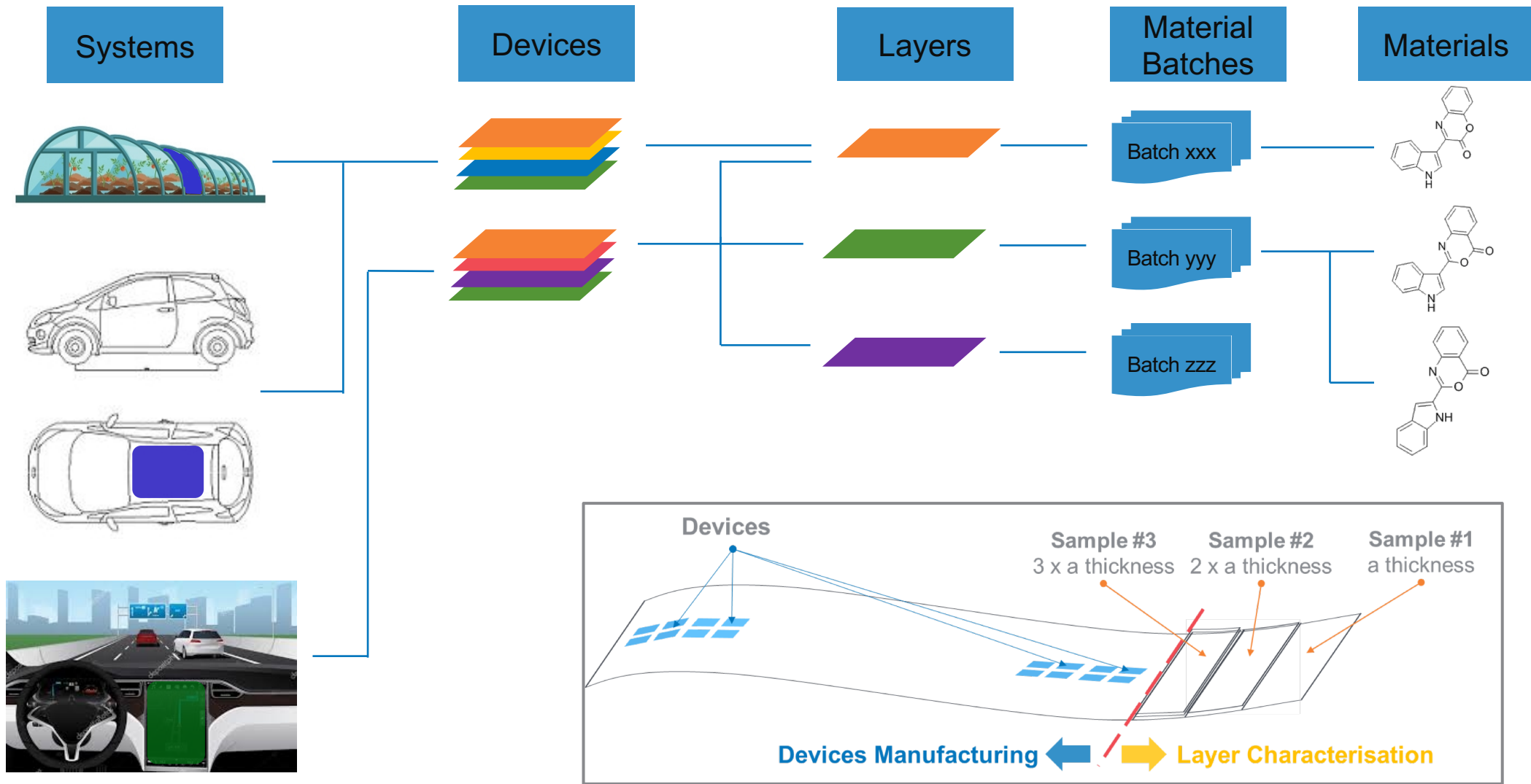
Electrostatics (field, mono, dipole)  
ME.EXTEN.UOI  
ME.ELEN.UOI  
ME.POLEN.UOI

Charge transfer (Marcus, KMC)  
ME.RATE.UOI  
ME.KMC.UOI

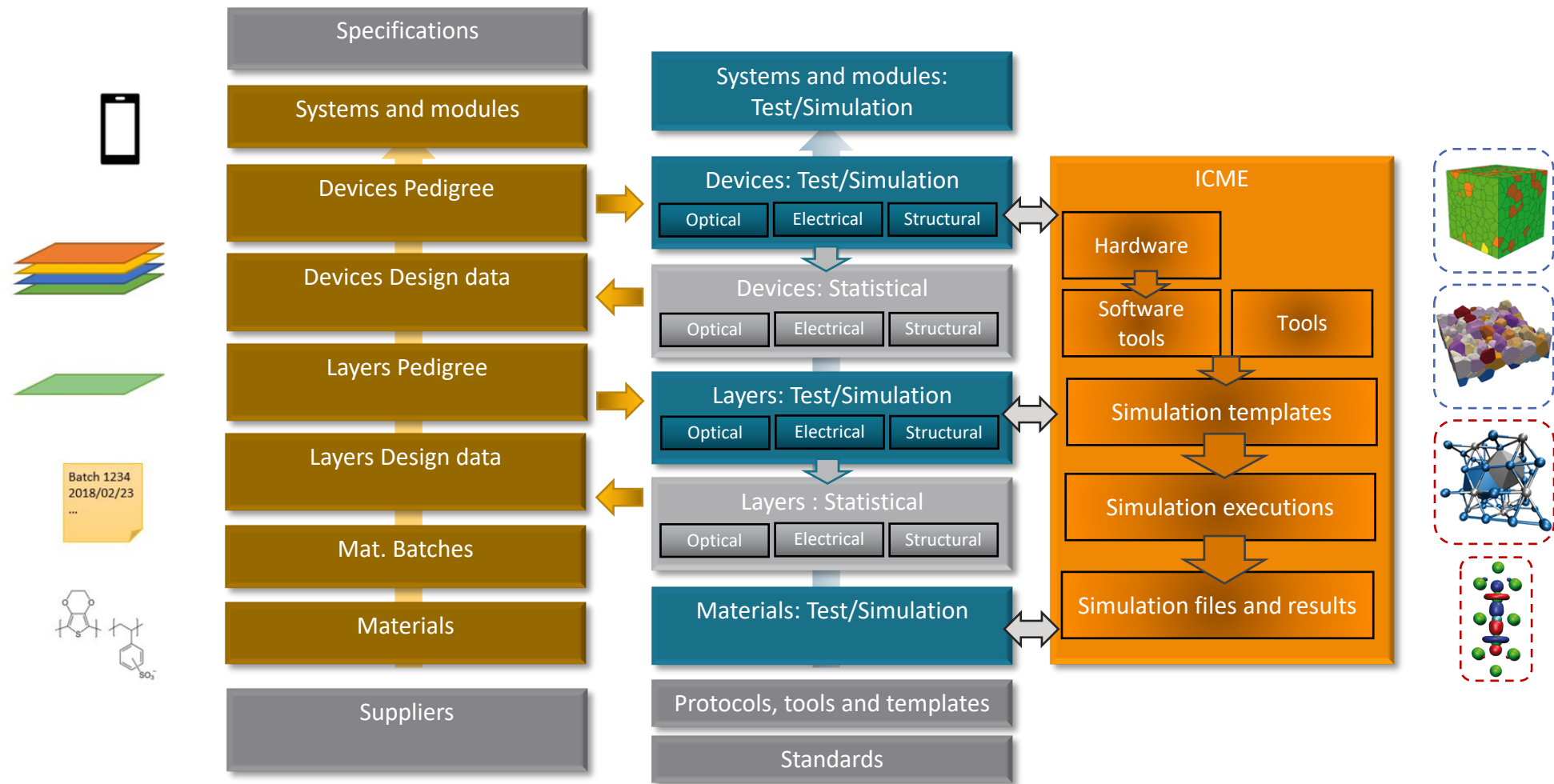
Protocol Chains spanning all length a



# CORNET: Characterisation of Multilayer Devices

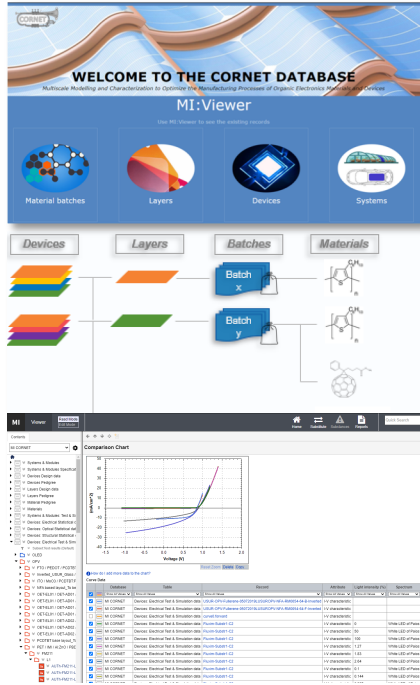


# CORNET: Materials Data Management Structure





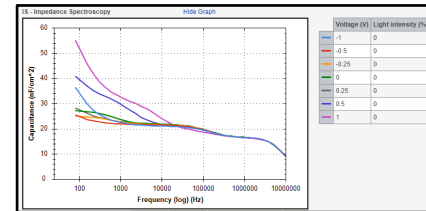
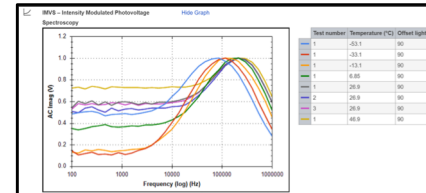
# CORNET: Summary of Developments



Data management for OE based on GRANTA MI technology

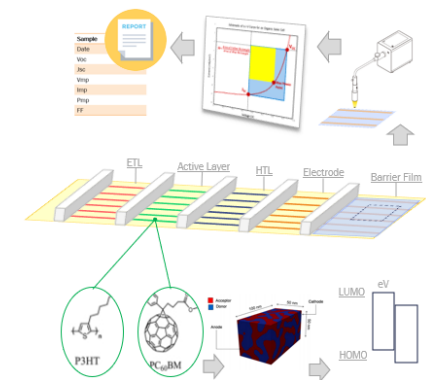
```

### COLUMN QUANTITIES:
# Column 1: Sweep 1 - Ramp Rate (V/s)
# Column 2: Sweep 2 - Inactive
# Column 3: Time (s)
# Column 4: Light Intensity (l)
# Column 5: LED Current (A)
# Column 6: Device Voltage (V)
# Column 7: Device Current (A)
# Column 8: Raw Voltage 1 (V)
# Column 9: Raw Voltage 2 (V)
# Column 10: Voltage Photodetector (V)
# Column 11: RC Current (A)
# Column 12: Luminance (cd)
# Column 13: Applied Voltage (V)
1.000000E+3 0.000000E+0 -1.462500E-3 6.091039E-7 -7.842012E-6
1.000000E+3 0.000000E+0 -1.483395E-3 6.091039E-7 -7.518445E-6
1.000000E+3 0.000000E+0 -1.444211E-3 6.091039E-7 -7.364707E-6
1.000000E+3 0.000000E+0 -1.435067E-3 6.091039E-7 -7.371392E-6
1.000000E+3 0.000000E+0 -1.425923E-3 6.091039E-7 -7.421092E-6
1.000000E+3 0.000000E+0 -1.416779E-3 6.091039E-7 -7.264443E-6
1.000000E+3 0.000000E+0 -1.407634E-3 6.091039E-7 -7.110192E-6
1.000000E+3 0.000000E+0 -1.398490E-3 6.091039E-7 -6.89497E-6
1.000000E+3 0.000000E+0 -1.389346E-3 6.091039E-7 -7.382602E-6
    
```

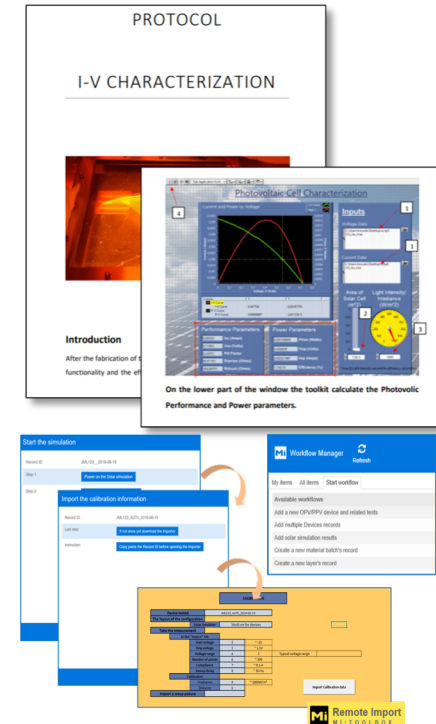


Capture of physical test data from electrical, structural and optical characterisation of OE devices, layers and materials

- ICME Simulation Templates
  - Subset Simulation Templates (Default)
    1. Protocols for electronic modeling (EL)
    2. Protocols for atomistic modeling (AT)
    3. Protocols for mesoscopic structural modeling (MS)
    4. Protocols for mesoscopic electrical modeling (ME)
    5. Protocols for continuum (device) level modeling (CO)



Collection of multi-scale materials modelling results and facilitation of model validation against physical test data



Digitalisation of characterisation and model validation protocols and capture of agreed metadata

# / CORNET: Acknowledgements & Contacts



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- Jean-Marc Lucatelli (Cornet schema and GRANTA MI database development)
- Andrea Berto, Davide Di Stefano, Ludovic Steinbach, David Cebon, Nic Austin, Donna Dykeman (ICME schema)
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